



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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Features

- $BV_{CEO} > -30V$
- $I_C = -1A$ High Continuous Current
- Excellent h_{FE} Characteristics up to $-2A$
- Low Saturation Voltage $V_{CE(sat)} < -0.35V @ -1A$
- Complementary NPN Type: NK-FZT489

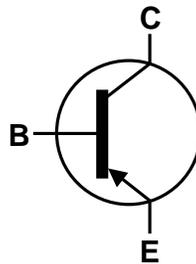
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.112 grams (Approximate)

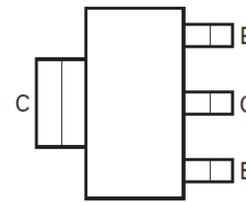
SOT223 (Type DN)



Top View



Device Symbol



Top View
Pin-Out

Absolute Maximum Ratings

 (@ $T_A = +25^{\circ}\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	-50	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-1	A
Peak Pulse Current	I_{CM}	-2	A

Thermal Characteristics

 (@ $T_A = +25^{\circ}\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	P_D	(Note 5)	2	W
		(Note 6)	3	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	(Note 5)	62.5	$^{\circ}\text{C/W}$
		(Note 6)	41.7	$^{\circ}\text{C/W}$
Thermal Resistance, Junction to Leads (Note 7)	$R_{\theta JL}$	19.4	$^{\circ}\text{C/W}$	
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^{\circ}\text{C}$	

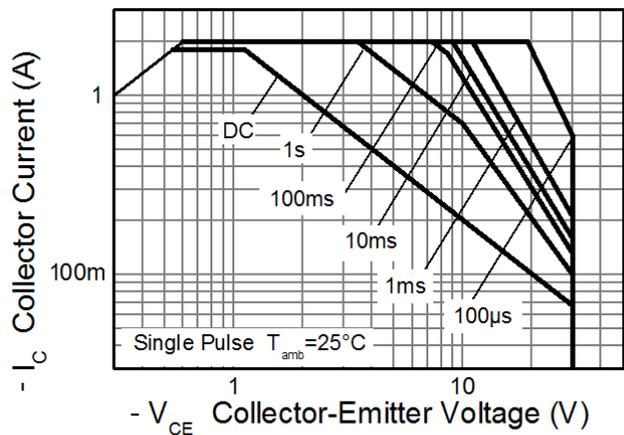
ESD Ratings

 (Note 8)

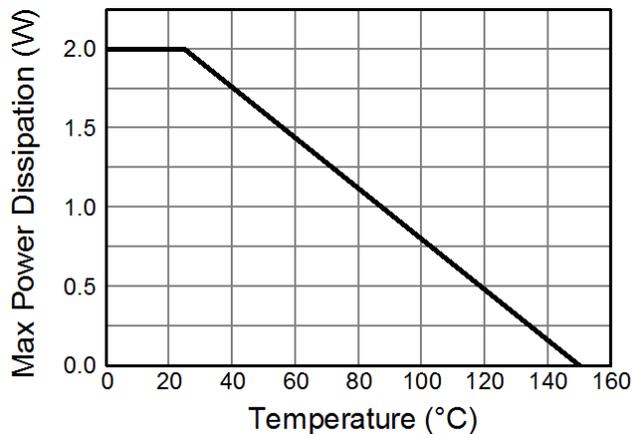
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 5, except the device is mounted on 50mm x 50mm single sided 2oz weight copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

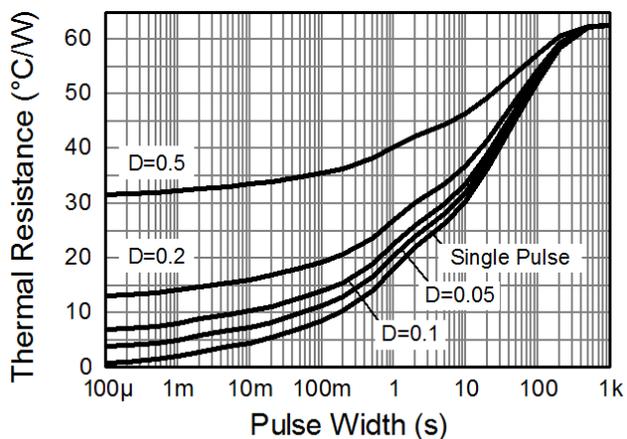
Thermal Characteristics and Derating Information



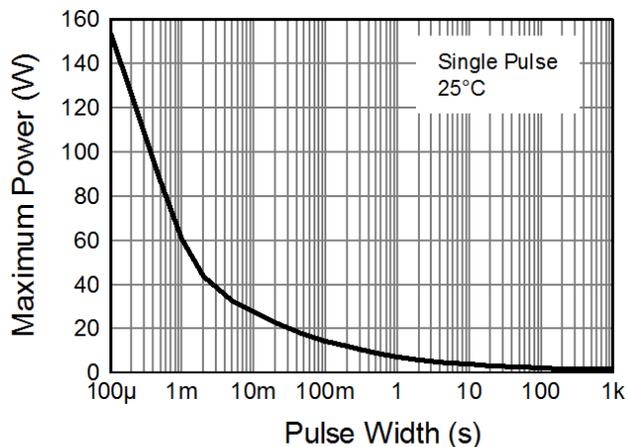
Safe Operating Area



Derating Curve



Transient Thermal Impedance



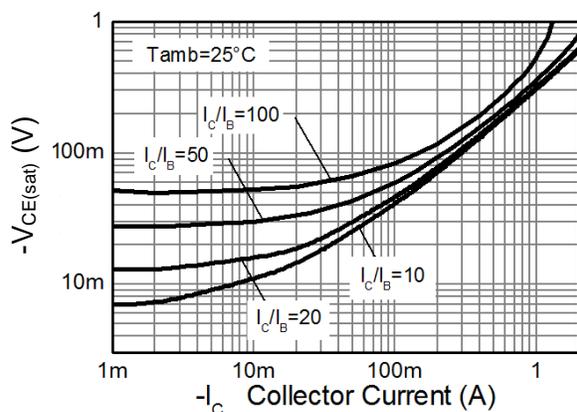
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

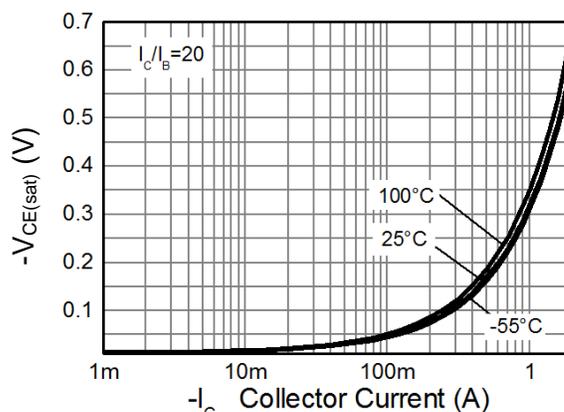
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CB0}	-50	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-30	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	—	-100	nA	V _{CB} = -30V
Collector Emitter Cut-Off Current	I _{CES}	—	—	-100	nA	V _{CE} = -30V
Emitter Cut-Off Current	I _{EBO}	—	—	-100	nA	V _{EB} = -4V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	—	-0.35 -0.65	V	I _C = -1A, I _B = -100mA I _C = -2A, I _B = -200mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	—	-1.2	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	—	-1.1	V	I _C = -1A, V _{CE} = -2V
DC Current Transfer Static Ratio (Note 9)	h _{FE}	100	—	—	—	I _C = -1mA, V _{CE} = -2V
		100	—	300	—	I _C = -500mA, V _{CE} = -2V
		80	—	—	—	I _C = -1A, V _{CE} = -2V
		40	—	—	—	I _C = -2A, V _{CE} = -2V
Transitional Frequency (Note 9)	f _T	100	—	—	MHz	V _{CE} = -5V, I _C = -100mA f = 100MHz
Output Capacitance (Note 9)	C _{obo}	—	—	15	pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on}	—	50	—	ns	I _C = -500mA, V _{CC} = -10V I _{B1} = -I _{B2} = -50mA
	t _{off}	—	300	—		

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

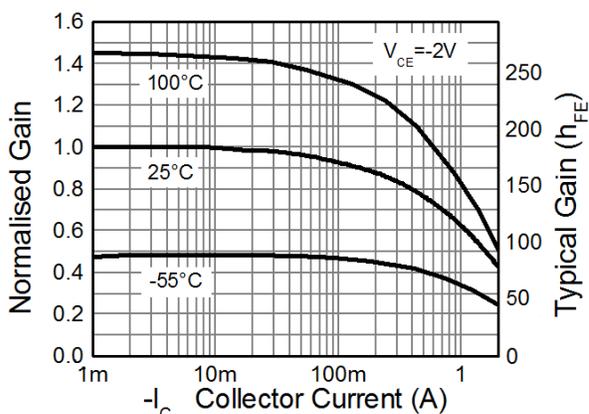
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



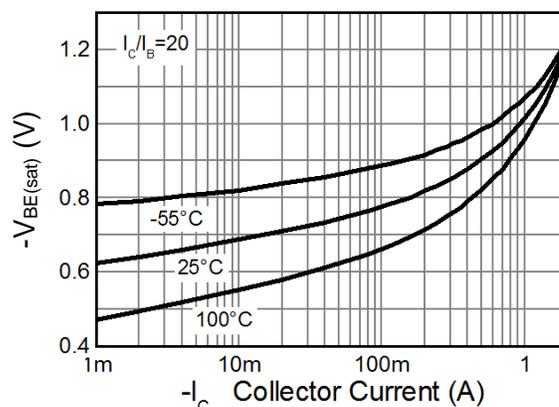
$V_{CE(sat)} \text{ v } I_C$



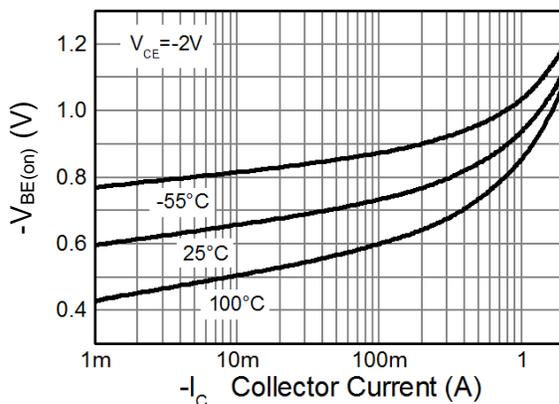
$V_{CE(sat)} \text{ v } I_C$



$h_{FE} \text{ v } I_C$



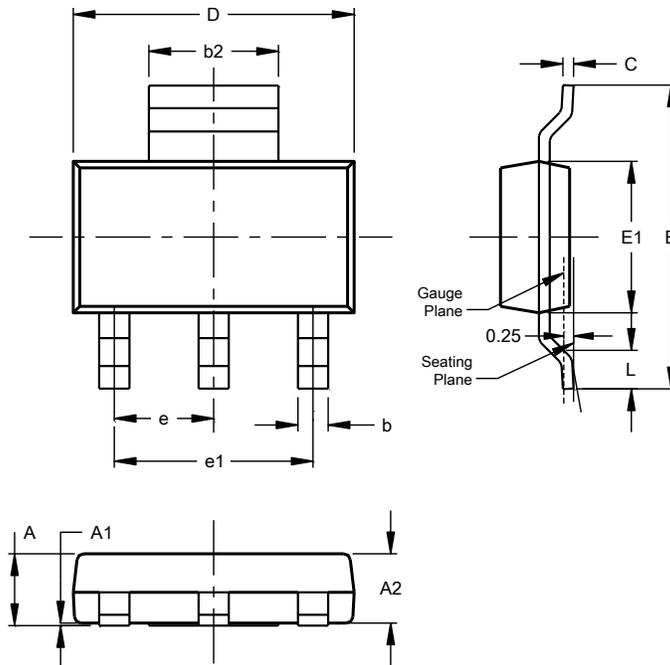
$V_{BE(sat)} \text{ v } I_C$



$V_{BE(on)} \text{ v } I_C$

Package Outline Dimensions

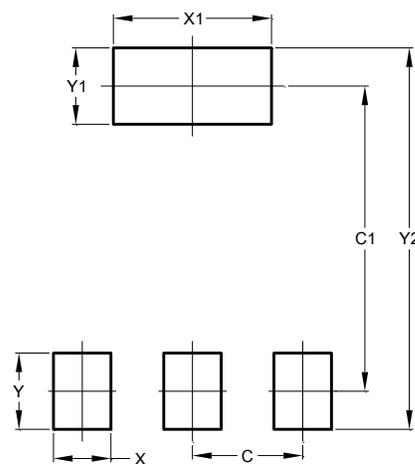
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Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00